

What is claimed is:

1. A method for determining the suitability of an optical material for the production of optical elements, particularly for high-energy light irradiation, with which radiation-induced absorption in the optical material is determined by radiating said optical material with excitation radiation and determining the total fluorescence which is induced via said radiation and which is composed of intrinsic and non-intrinsic portions, wherein the non-intrinsic fluorescence is determined, as the fluorescence, during and/or immediately following radiation.

2. The method as recited in Claim 1, wherein the intrinsic fluorescence is also determined and the suitability of the material is determined based on the ratio of intrinsic and non-intrinsic fluorescence.

3. The method as recited in one of the preceding Claims, wherein the material is irradiated for a short period of time.

4. The method as recited in one of the preceding Claims, wherein the irradiation is carried out using a laser pulse.

5. The method as recited in one of the preceding Claims, wherein the fluorescence is determined using an I-CCD camera.

6. The method as recited in one of the preceding Claims, wherein the determination is carried out using a grating spectrograph.

7. The method as recited in one of the preceding Claims, wherein, before the fluorescence is determined, the wavelength of the excitation radiation is hidden using a suitable device.

1 8. The method as recited in Claim 7,  
2 wherein the device is a filter and/or a spectral grating.

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4 9. The method as recited in one of the preceding Claims,  
5 wherein the fluorescence is determined within the decay time of the non-intrinsic  
6 fluorescence after the optical material is irradiated.

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8 10. The method as recited in one of the preceding Claims,  
9 wherein the optical material is  $\text{CaF}_2$ ,  $\text{BaF}_2$ ,  $\text{SrF}_2$ ,  $\text{LiF}$ ,  $\text{NaF}$ ,  $\text{MgF}_2$  and/or  $\text{KMgF}_3$ .

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11 11. The method as recited in one of the preceding Claims,  
12 wherein, when an intrinsic fluorescence band appears, it is used to standardize  
13 the non-intrinsic fluorescence bands.

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15 12. The method as recited in one of the preceding Claims,  
16 wherein the material is pre-irradiated until the rapid damage is saturated before  
17 the determination using laser irradiation.

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19 13. The method as recited in one of the preceding Claims,  
20 wherein the radiation-induced absorption is accomplished using a comparable  
21 energy density.

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23 14. A device for carrying out the method as recited in one of the Claims 1  
24 through 13, including a source for transmitting excitation radiation that defines a  
25 light path, a holder for a material sample to be determined, the material sample  
26 being positioned in the light path, and a device located outside the light path for  
27 determining a fluorescence induced in the material sample by the excitation  
28 radiation,  
29 wherein a barrier element is located between the sample and the device for  
30 determining the fluorescence that prevents passage by the high-energy  
31 excitation radiation.

1 15. The use of the optical material obtained with the method as recited in one  
2 of the Claims 1 through 13 or by using the device as recited in Claim 14 for the  
3 production of lenses, prisms, light-conducting rods, optical windows, optical  
4 components for DUV photolithography, steppers, excimer lasers, wafers,  
5 computer chips, and integrated circuits and electronic devices that contain  
6 circuits and chips of this type.